

Advanced Semiconductor Fundamentals Solution Manual

Analog circuit and system design today is more essential than ever before. With the growth of digital systems, wireless communications, complex industrial and automotive systems, designers are challenged to develop sophisticated analog solutions. This comprehensive source book of circuit design solutions will aid systems designers with elegant and practical design techniques that focus on circuit application examples provide insight into circuit design and application solutions that you can apply in today's demanding designs. Covers the fundamentals of linear/analog circuit and system design to guide engineers with their design challenges. Based on the Application Notes of Linear Technology, the foremost designer of high performance analog products, readers will gain practical insights in the design of precision amplifiers, comparators, data converters, signal conditioning, and high frequency/RF design. Contributors include the leading lights in analog design: Robert Dotkin, Jim Williams and Carl Nelson, among others.

The most up-to-date book available on the physics of photonic devices. This new edition of Physics of Photonic Devices incorporates significant advancements in the field of photonics that have occurred since publication of the first edition (Physics of Optoelectronic Devices). New topics covered include a brief history of the invention of semiconductor lasers, the Lorentz dipole method and metal plasmon waveguides, optical ring resonators, integrated electroabsorption modulator-lasers, and solar cells. It also introduces exciting new fields of research such as: surface plasmonics and micro-ring resonators; the theory of optical gain and absorption in quantum dots and quantum wires and their applications in semiconductor lasers; and novel microcavity and photonic crystal lasers, quantum-cascade lasers, and advanced semiconductor lasers. Physics of Photonic Devices, Second Edition presents novel information that is not yet available in book form elsewhere. Many problem sets have been updated, the answers to which are available in an all-new Solutions Manual for instructors. Comprehensive, timely, and practical, Physics of Photonic Devices is an invaluable textbook for advanced undergraduate and indispensable tool for researchers working in this rapidly growing field.

Semiconductor Devices: Physics and Design teaches readers how to approach device design from the point of view of someone who wants to improve devices and can see the opportunity and challenges. It begins with coverage of basic physics concepts, including the physics behind polar heterostructures and strained heterostructures. The book then details the important devices ranging from power device design to device performance and then relating device needs to system use. The student can see how device design works in the real world.

Capitalist Nigger is an explosive and jarring indictment of the black race. The book asserts that the Negroid race, as naturally endowed as any other, is culpably a non-productive race, a consumer race that depends on other communities for its culture, its language, its feeding and its clothing. Despite enormous natural resources, blacks are economic slaves because they lack the 'devil-may-care' as well as the spider web mentality of the Asian. A Capitalist Nigger must embody ruthlessness in pursuit of excellence in his drive towards achieving the goal of becoming an economic warrior. In putting forward the idea of the Capitalist Nigger, Chika Onyeali charts a road to success whereby black economic warriors employ the 'Spider Web Doctrine' - discipline, self-reliance, ruthlessness - to

Nigeria, Chika Onyeali is a journalist, editor and former diplomat.

Electronic Properties of Materials

Introduction to Soil Mechanics

With Applications in Excel

The Road To Success – A Spider Web Doctrine

Semiconductor Fundamentals

Advanced Semiconductor Fundamentals

Special Features *Computer-based exercises and homework problems -- unique to this text and comprising 25% of the total number of problems -- encourage students to address realistic and challenging problems, experiment with what if scenarios, and easily obtain graphical outputs. Problems are designed to progressively enhance MATLAB-use proficiency, so students need not be familiar with MATLAB at the start of your course. Program scripts that are answers to exercises in the text are available at no charge in electronic form (see Teaching Resources below). *Supplement and Review Mini-Chapters after each of the text's three parts contain an extensive review list of terms, test-like problem sets with answers, and detailed suggestions on supplemental reading to reinforce students' learning and help them prepare for exams. *Read-Only Chapters, strategically placed to provide a change of pace during the course, provide informative, yet enjoyable reading for students. *Measurement Details and Results samples offer students a realistic perspective on the seldom-perfect nature of device characteristics, contrary to the way they are often represented in introductory texts. Content Highlight

This book covers the fundamentals and significance of 2-D materials and related semiconductor transistor technologies for the next-generation ultra low power applications. It provides comprehensive coverage on advanced low power transistors such as NCFETs, FinFETs, TFETs, and flexible transistors for future ultra low power applications owing to their better subthreshold swing and scalability. In addition, the text examines the use of field-effect transistors for biosensing applications and covers design considerations and compact modeling of advanced low power transistors such as NCFETs, FinFETs, and TFETs. TCAD simulation examples are also provided. FEATURES Discusses the latest updates in the field of ultra low power semiconductor transistors Provides both experimental and analytical solutions for TFETs and NCFETs Presents synthesis and fabrication processes for FinFETs Reviews details on 2-D materials and 2-D transistors Explores the application of FETs for biosensing in the healthcare field This book is aimed at researchers, professionals, and graduate students in electrical engineering, electronics and communication engineering, electron devices, nanoelectronics and nanotechnology, microelectronics, and solid-state circuits.

This book presents those terms, concepts, equations, and models that are routinely used in describing the operational behavior of solid state devices. The second edition provides many new problems and illustrative examples.

The devices described in "Advanced MOS-Gated Thyristor Concepts" are utilized in microelectronics production equipment, in power transmission equipment, and for very high power motor control in electric trains, steel-mills, etc. Advanced concepts that enable improving the performance of power thyristors are discussed here, along with devices with blocking voltage capabilities of 5,000-V, 10,000-V and 15,000-V. Throughout the book, analytical models are generated to allow a simple analysis of the structures and to obtain insight into the underlying physics. The results of two-dimensional simulations are provided to corroborate the analytical models and give greater insight into the device operation.

An Applied Approach

Analog Circuit Design

Fundamentals of Semiconductors

Field Effect Devices

Physics of Photonic Devices

Fundamentals of Solid-State Electronics

This text aims to provide the fundamentals necessary to understand semiconductor device characteristics, operations and limitations. Quantum mechanics and quantum theory are explored, and this background helps give students a deeper understanding of the essentials of physics and semiconductors.

An engaging writing style and a strong focus on the physics make this graduate-level textbook a must-have for electromagnetics students.

During the last decade many new concepts have been proposed for improving the performance of power MOSFETs. The results of this research are dispersed in the technical literature among journal articles and abstracts of conferences. Consequently, the information is not readily available to researchers and practicing engineers in the power device community. There is no cohesive treatment of the ideas to provide an assessment of the relative merits of the ideas. "Advanced Power MOSFET Concepts" provides an in-depth treatment of the physics of operation of advanced power MOSFETs. Analytical models for explaining the operation of all the advanced power MOSFETs will be developed. The results of numerical simulations will be provided to give additional insight into the device physics and validate the analytical models. The results of two-dimensional simulations will be provided to corroborate the analytical models and give greater insight into the device operation.

Introduction to Soil Mechanics, Béla Bódi & Colin Jones Introduction to Soil Mechanics covers the basic principles of soil mechanics, illustrating why the properties of soil are important, the techniques used to understand and characterise soil behaviour and how that knowledge is then applied in construction. The authors have endeavoured to define and discuss the principles and concepts concisely, providing clear, detailed explanations, and a well-illustrated text with diagrams, charts, graphs and tables. With many practical, worked examples and end-of-chapter and coverage of Eurocode 7, Introduction to Soil Mechanics will be an ideal starting point for the study of soil mechanics and geotechnical engineering. About the Authors Béla Bódi B.Sc., B.A., C.Eng., M.I.C.E. was born in Hungary and studied at Budapest Technical University, the University of London and the Open University. He developed his expertise in Soil Mechanics during his employment with British Rail and British Coal. B.Sc. Eng., M.I.C.E., P.E.C.E. studied at the University of Dundee, and worked at British Coal where he and Béla were colleagues. He has recently retired from the University of Wales, Newport where he was Programme Director for the Civil Engineering provision, specializing in Soil Mechanics and Geotechnics. Also Available Fundamentals of Rock Mechanics 4th Edition J C Jaeger, N G W Cook and R Zimmerman Hardcover: 9780632057597 Smith's Elements of Soil Mechanics 8th Edition Ian Smith Paperback: 9781405133708

Semiconductor Fundamentals

Semiconductor Device Physics and Design

Basic Principles

The IGBT Device

Semiconductor Device Fundamentals

Fundamentals of Modern Manufacturing

From theory and fundamentals to the latest advances in computational and experimental modal analysis, this is the definitive, updated reference on structural dynamics. This edition updates Professor Craig's classic introduction to structural dynamics, which has been an invaluable resource for practicing engineers and a textbook for undergraduate and graduate courses in vibrations and/or structural dynamics. Along with comprehensive coverage of structural dynamics fundamentals, finite-element-based computational methods, and dynamic testing methods, this Second Edition includes new and expanded coverage of computational methods, as well as introductions to more advanced topics, including experimental modal analysis and "active structures." With a systematic approach, it presents solution techniques that apply to various engineering disciplines. It discusses single degree-of-freedom (SDOF) systems, multiple degrees-of-freedom (MDOF) systems, and continuous systems in depth; and includes numeric evaluation of modes and frequency of MDOF systems; direct integration methods for dynamic response of SDOF systems and MDOF systems; and component mode synthesis. Numerous illustrative examples help engineers apply the techniques and methods to challenges they face in the real world. MATLAB(r) is extensively used throughout the book, and many of the .m-files are made available on the book's Web site. Fundamentals of Structural Dynamics, Second Edition is an indispensable reference and "refresher course" for engineering professionals; and a textbook for seniors or graduate students in mechanical engineering, civil engineering, engineering mechanics, or aerospace engineering.

A practical guide to semiconductor manufacturing from processcontrol to yield modeling and experimental design Fundamentals of Semiconductor Manufacturing and Process Controlcovers all issues involved in manufacturing microelectronic devicesand circuits, including fabrication sequences, process control,experimental design, process modeling, yield modeling, and CIM/CAMsystems. Readers are introduced to both the theory and practice ofall basic manufacturing concepts. Following an overview of manufacturing and technology, the textexplores process monitoring methods, including those that focus onproduct wafers and those that focus on the equipment used toproduce wafers. Next, the text sets forth some fundamentals ofstatistics and yield modeling, which set the foundation for adetailed discussion of how statistical process control is used toanalyze quality and improve yields. The discussion of statistical experimental design offers readers a powerful approach for systematically varying controllable processconditions and determining their impact on output parameters thatmeasure quality. The authors introduce process modeling concepts,including several advanced process control topics such asrun-by-run, supervisory control, and process and equipmentdiagnosis. Critical coverage includes the following: * Combines process control and semiconductor manufacturing * Unique treatment of system and software technology and management of overall manufacturing systems * Chapters include case studies, sample problems, and suggestedexercises * Instructor support includes electronic copies of the figures and an instructor's manual Graduate-level students and industrial practitioners will benefitfrom the detailed examination of how electronic materials andsupplies are converted into finished integrated circuits andelectronic products in a high-volume manufacturingenvironment. An Instructor's Manual presenting detailed solutions to all problems in the book is available from the Wiley editorialdepartment. An Instructor Support FTP site is also available.

Excellent bridge between general solid-state physics textbook and research articles packed with providing detailed explanations of the electronic, vibrational, transport, and optical properties of semiconductors. The most striking feature of the book is its modern outlook ... provides a wonderful foundation ... the most wonderful feature is its efficient style of exposition ... an excellent book." Physics Today "Presents the theoretical derivations carefully and in detail and gives thorough discussions of the experimental results it presents. This makes it an excellent textbook both for learners and for more experienced researchers wishing to check facts. I have enjoyed reading it and strongly recommend it as a text for anyone working with semiconductors. ... I know of no better text. ... I am sure most semiconductor physicists will find this book useful and I recommend it to them." Contemporary Physics Offers much new material: an extensive appendix about the important and by and now well-established, deep center known as the DX center, additional problems and the solutions to over fifty of the problems at the end of the various chapters.

This updated, second edition textbook provides a thorough and accessible treatment of semiconductor lasers from a design and engineering perspective. It includes both the physics of devices as well as the engineering, designing and testing of practical lasers. The material is presented clearly with many examples provided. Readers of the book will come to understand the finer aspects of the theory, design, fabrication and test of these devices and have an excellent background for further study of optoelectronics.

Semiconductor Devices and Technologies for Future Ultra Low Power Electronics

Mechanics of Materials

Fundamentals of Electrochemical Deposition

Fundamentals and Applications

Advanced Power Rectifier Concepts

Solutions Manual

Simple and Flexible, MODERN PHYSICS, Third Edition has been specifically designed to provide simple, clear, and mathematically uncomplicated explanations of physical concepts and theories of modern physics. The authors clarify and show support for these theories through a broad range of current applications and examples-attempting to answer questions such as: What holds molecules together? How do electrons tunnel through barriers? How do electrons move through solids? How can currents persist indefinitely in superconductors? To pique student interest, brief sketches of the historical development of twentieth-century physics such as anecdotes and quotations from key figures as well as interesting photographs of noted scientists and original apparatus are integrated throughout. The Third Edition has been extensively revised to clarify difficult concepts and thoroughly updated to include rapidly developing technical applications in quantum physics. To complement the analytical solutions in the text and to help students visualize abstract concepts, the new edition also features free online access to QTools, new platform-independent simulation software created by co-author, Curt Moyer, and developed with support from the National Science Foundation. Icons in the text indicate the problems designed for use with the software. Important Notice: Media content referenced within the product description or the product text may not be available in the ebook version.

Resistivity -- Carrier and doping density -- Contact resistance and Schottky barriers -- Series resistance, channel length and width, and threshold voltage -- Defects -- Oxide and interface trapped charges, oxide thickness -- Carrier lifetimes -- Mobility -- Charge-based and probe characterization -- Optical characterization -- Chemical and physical characterization -- Reliability and failure analysis.

Optical Sources, Detectors, and Systems presents a unified approach, from the applied engineering point of view, to radiometry, optical devices, sources, and receivers. One of the most important and unique features of the book is that it combines modern optics, electric circuits, and system analysis into a unified, comprehensive treatment. The text provides physical concepts together with numerous data for sources and systems and offers basic analytical tools for a host of practical applications. Convenient reference sources, such as a glossary with explanatory text for scientific optical terminology, are included. Also, there are many illustrative examples and problems with solutions. The book covers many important, diverse areas such as medical thermography, fiber optical communications, and CCD cameras. It also explains topics such as d *, NEP, f number, RA product, BER, shot noise, and more. This volume can be considered an essential reference for research and practical scientists working with optical and infrared systems, as well as a text for graduate-level courses on optoelectronics, optical sources and systems, and optical detection. A problem solution manual for instructors who wish to adopt this text is available. Provides a unified treatment of optical sources, detectors, and applications Explains d *, NEP, f number, RA product, BER, shot noise, and more Contains numerous illustrative examples and exercises with solutions Extensively illustrated with more than 90 drawings and graphs

During the last decade, many new concepts have been proposed for improving the performance of power rectifiers and transistors. The results of this research are dispersed in the technical literature among journal articles and abstracts of conferences. Consequently, the information is not readily available to researchers and practicing engineers in the power device community. There is no cohesive treatment of the ideas to provide an assessment of the relative merits of the ideas. Advanced Power Rectifier Concepts provides an in-depth treatment of the physics of operation of advanced power rectifiers. Analytical models for explaining the operation of all the advanced power rectifier devices will be developed. The results of numerical simulations will be provided to provide additional insight into the device physics and validate the analytical models. The results of two-dimensional simulations will be provided to corroborate the analytical models and provide greater insight into the device operation.

Fundamentals of Semiconductor Devices

A Modern Approach to Classical Theorems of Advanced Calculus

A Tutorial Guide to Applications and Solutions

Physics, Design and Applications of the Insulated Gate Bipolar Transistor

Classical Fortran

Processes and Systems

The Third Edition of the standard textbook and reference in the field of semiconductor devices This classic book has set the standard for advanced study and reference in the semiconductor device field. Now completely updated and reorganized to reflect the tremendous advances in device concepts and performance, this Third Edition remains the most detailed and exhaustive single source of information on the most important semiconductor devices. It gives readers immediate access to detailed descriptions of the underlying physics and performance characteristics of all major bipolar, field-effect, microwave, photonic, and sensor devices. Designed for graduate textbook adoptions and reference needs, this new edition includes: A complete update of the latest developments New devices such as three-dimensional MOSFETs, MODFETs, resonant-tunneling diodes, semiconductor sensors, quantum-cascade lasers, single-electron transistors, real-space transfer devices, and more Materials completely reorganized Problem sets at the end of each chapter All figures reproduced at the highest quality Physics of Semiconductor Devices, Third Edition offers engineers, research scientists, faculty, and students a practical basis for understanding the most important devices in use today and for evaluating future device performance and limitations. A Solutions Manual is available from the editorial board.

Modern Semiconductor Devices for Integrated Circuits, First Edition introduces readers to the world of modern semiconductor devices with an emphasis on integrated circuit applications. KEY TOPICS: Electrons and Holes in Semiconductors; Motion and Recombination of Electrons and Holes; Device Fabrication Technology; PN and Metal-Semiconductor Junctions; MOS Capacitor; MOS Transistor; MOSFETs in ICs—Scaling, Leakage, and Other Topics; Bipolar Transistor. MARKET: Written by an experienced teacher, researcher, and expert in industry practices, this succinct and forward-looking text is appropriate for anyone interested in semiconductor devices for integrated circuits, and serves as a suitable reference text for practicing engineers.

The IGBT device has proved to be a highly important Power Semiconductor, providing the basis for adjustable speed motor drives (used in air conditioning and refrigeration and railway locomotives), electronic ignition systems for gasolinepowered vehicles and energy-saving compact fluorescent light bulbs. Recent applications include plasma displays (flat-screen TVs) and electric power transmission systems, alternative energy systems and energy storage. This book is the first available to cover the applications of the IGBT, and provide the essential information needed by applications engineers to design new products using the device, in sectors including consumer, industrial, lighting, transportation, medical and renewable energy. The author, B. Jayant Baliga, invented the IGBT in 1980 while working for GE. His book will unlock IGBT for a new generation of engineering applications, making it essential reading for a wide audience of electrical engineers and design engineers, as well as an important publication for semiconductor specialists. Essential design information for applications engineers utilizing IGBTs in the consumer, industrial, lighting, transportation, medical and renewable energy sectors. Readers will learn the methodologies for the design of IGBT chips including edge terminations, cell topologies, gate layouts, and integrated current sensors. The first book to cover

Books are seldom finished. At best, they are abandoned. The second edition of "Electronic Properties of Materials" has been in use now for about seven years. During this time my publisher gave me ample opportunities to update and improve the text whenever the book was reprinted. There were about six of these reprinting cycles. Eventually, however, it became clear that substantially more new material had to be added to account for the stormy developments which occurred in the field of electrical, optical, and magnetic materials. In particular, expanded sections on flat-panel displays (liquid crystals, electroluminescence devices, field emission displays, and plasma dis.) plays) were added. Further, the recent developments in blue- and green emitting LED's and in photonics are included. Magnetic storage devices also underwent rapid development. Thus, magneto-optical memories, magneto resistance devices, and new' magnetic materials needed to be covered. The sections on dielectric properties, ferroelectricity, piezoelectricity, electrostrictio, and thermoelectric properties have been expanded. Of course, the entire text was critically reviewed, updated, and improved. However, the most extensive change I undertook was the conversion of all equations to SI units throughout. In most of the world and in virtually all of the international scientific journals use of this system of units is required. If today's students do not learn to utilize it, another generation is "lost" on this matter. In other words, it is important that students become comfortable with SI units.

Semiconductor Material and Device Characterization

Modern Physics

Semiconductor Devices, Physics and Technology

Modern Semiconductor Devices for Integrated Circuits

Programming for Engineering and Scientific Applications, Second Edition

Capitalist Nigger

Classical FORTRAN: Programming for Engineering and Scientific Applications, Second Edition teaches how to write programs in the classical dialect of FORTRAN, the original and still most widely recognized language for numerical computing. This edition retains the conversational style of the original, along with its simple, carefully chosen subset language and its focus on floating-point calculations. New to the Second Edition Additional case study on file I/O More about CPU timing on Pentium processors More about the g77 compiler and Linux With numerous updates and revisions throughout, this second edition continues to use case studies and examples to introduce the language elements and design skills needed to write graceful, correct, and efficient programs for real engineering and scientific applications. After reading this book, students will know what statements to use and where as well as why to avoid the others, helping them become expert FORTRAN programmers.

This book uses elementary versions of modern methods found in sophisticated mathematics to discuss portions of "advanced calculus" in which the subtlety of the concepts and methods makes rigor difficult to attain at an elementary level.

This book presents the underlying functional formalism routinely used in describing the operational behavior of solid state devices.

This Solutions Manual, a companion volume of the book, Fundamentals of Solid-State Electronics, provides the solutions to the selected problems listed in the book. Most of the solutions are for the selected problems that had been assigned to the engineering undergraduate students who were taking an introductory device core course using this book. This Solution Manual also contains an extensive appendix which illustrates the application of the fundamentals to solutions of state-of-the-art transistor reliability problems which have been taught to advanced undergraduate and graduate students.

Health Economics

Fundamentals of Structural Dynamics

Optical Sources, Detectors, and Systems

Advanced High Voltage Power Device Concepts

Physics of Semiconductor Devices

Physics and Materials Properties

The second edition examines in detail three of the most basic members of the field device family to introduce the reader to relevant terms, concepts, models, and analytical procedures.

This Solution Manual, a companion volume of the book, Fundamentals of Solid-State Electronics, provides the solutions to selected problems listed in the book. Most of the solutions are for the selected problems that had been assigned to the engineering undergraduate students who were taking an introductory device core course using this book. This Solution Manual also contains an extensive appendix which illustrates the application of the fundamentals to solutions of state-of-the-art transistor reliability problems which have been taught to advanced undergraduate and graduate students. This book is also available as a set with Fundamentals of Solid-State Electronics and Fundamentals of Solid-State Electronics – Study Guide.

Fundamentals of Semiconductor Devices provides a realistic and practical treatment of modern semiconductor devices. A solid understanding of the physical processes responsible for the electronic properties of semiconductor materials and devices is emphasized. With this emphasis, the reader will appreciate the underlying physics behind the equations derived and their range of applicability. The author's clear writing style, comprehensive coverage of the core material, and attention to current topics are key strengths of this book.

The new edition of the most detailed and comprehensive single-volume reference on major semiconductor devices The Fourth Edition of Physics of Semiconductor Devices remains the standard reference work on the fundamental physics and operational characteristics of all major bipolar, unipolar, special microwave, and optoelectronic devices. This fully updated and expanded edition includes approximately 1,000 references to original research papers and review articles, more than 650 high-quality technical illustrations, and over two dozen tables of material parameters. Divided into five parts, the text first provides a summary of semiconductor properties, covering energy band, carrier concentration, and transport properties. The second part surveys the basic building blocks of semiconductor devices, including p-n junctions, metal-semiconductor contacts, and metal-insulator-semiconductor (MIS) capacitors. Part III examines bipolar transistors, MOSFETs (MOS field-effect transistors), and other field-effect transistors such as JFETs (junction field-effect-transistors) and MESFETs (metal-semiconductor field-effect transistors). Part IV focuses on negative-resistance and power devices. The book concludes with coverage of photonic devices and sensors, including light-emitting diodes (LEDs), solar cells, and various photodetectors and semiconductor sensors. This classic volume, the standard textbook and reference in the field of semiconductor devices: Provides the practical foundation necessary for understanding the devices currently in use and evaluating the performance and limitations of future devices Offers completely updated and revised information that reflects advances in device concepts, performance, and application Features discussions of topics of contemporary interest, such as applications of photonic devices that convert optical energy to electric energy Includes numerous problem sets, real-world examples, tables, figures, and illustrations; several useful appendices; and a detailed solutions manual for Instructor's only Explores new work on leading-edge technologies such as MODFETs, resonant-tunneling diodes, quantum-cascade lasers, single-electron transistors, real-space-transfer devices, and MOS-controlled thyristors Physics of Semiconductor Devices, Fourth Edition is an indispensable resource for design engineers, research scientists, industrial and electronics engineering managers, and graduate students in the field.

Calculus on Manifolds

Fundamentals of Semiconductor Manufacturing and Process Control

Introduction to Semiconductor Lasers for Optical Communications

Solution Manual

Solution's manual

Semiconductor Physics and Devices

This book takes a modern, all-inclusive look at manufacturing processes. Its coverage is strategically divided—63% concerned with manufacturing process technologies, 35% dealing with engineering materials and production systems.

Fundamentals of Power Semiconductor Devices provides an in-depth treatment of the physics of operation of power semiconductor devices that are commonly used by the power electronics industry. Analytical models for explaining the operation of all power semiconductor devices are shown. The treatment here focuses on silicon devices but includes the unique attributes and design requirements for emerging silicon carbide devices. The book will appeal to practicing engineers in the power semiconductor device community.

Comprehensive in coverage this textbook, written by academics from leading institutions, discusses current developments and debates in modern health economics from an international perspective. Economic models are presented in detail, complemented by real-life explanations and analysis, and discussions of the influence of such theories on policymaking. Offering sound pedagogy and economic rigor, Health Economics focuses on building intuition alongside appropriate mathematical formality, translating technical language into accessible economic narrative. Rather than shyng away from intellectual building blocks, students are introduced to technical and theoretical foundations and encouraged to apply these to inform empirical studies and wider policymaking. Health Economics provides - A broad scope, featuring comparative health policy and empirical examples from around the world to help students relate the principles of health economics to everyday life - Coverage of topical issues such as the obesity epidemic, economic epidemiology, socioeconomic health disparities, and behavioural economics - A rich learning resource, complete with hundreds of exercises to help solidify and extend understanding. This book is designed for advanced undergraduate courses in health economics and policy but may also interest postgraduate students in economics, medicine and health policy.

Mechanics of Materials: With Applications in Excel® covers the fundamentals of the mechanics of materials—in a clear and easily understandable way. Each chapter explains the theory of the underlying principles and the applicable mathematical relations, offering examples that illustrate the application of the mathematical relations to physical situations. Then, homework problems—arranged from the simplest to the most demanding—are presented, along with a number of challenging review problems, to ensure comprehension of key concepts. What makes this book unique is that it also instills practical skills for developing Microsoft Excel applications to solve mechanics of materials problems using numerical techniques. Mechanics of Materials: With Applications in Excel® provides editable Excel spreadsheets representing all the examples featured in the text, PowerPoint lecture slides, multimedia simulations, graphics files, and a solutions manual with qualifying course adoption.

Modern Electrodeposition

Fundamentals of Solid-state Electronics

Advanced Power MOSFET Concepts

Fundamentals of Power Semiconductor Devices

Excellent teaching and resource material. . . It is concise, coherently structured, and easy to read. . . highly recommended for students, engineers, and researchers in all related fields. - Corrosion on the First Edition of Fundamentals of Electrochemical Deposition From computer hardware to automobiles, medical diagnostics to aerospace, electrochemical deposition plays a crucial role in an array of key industries. Fundamentals of Electrochemical Deposition, Second Edition is a comprehensive introduction to today's most advanced fields of practical knowledge. The most authoritative introduction to the field so far, the book presents detailed coverage of the full range of electrochemical deposition processes and techniques, including "Metal-solution interphase," "Charge transfer across an interphase," "Formation of an equilibrium electrode potential," "Nucleation and growth of thin films," "Kinetics and mechanisms of electrodeposition," "Electroless deposition," "In situ characterization of deposition processes," "Structure and properties of deposits," "Multilayered and composite thin films," "Interdiffusion in thin film," "Applications in the semiconductor industry and the field of medicine This new edition updates the prior edition to address the new developments in the science and its applications, with new chapters on innovative applications of electrochemical deposition in semiconductor technology, magnetism and microelectronics, and medical instrumentation. Added coverage includes such topics as binding energy, nanoclusters, atomic force, and scanning tunneling microscopy. Example problems at the end of chapters and other features clarify and improve understanding of the material. Written by an author team with extensive experience in both industry and academe, this reference and text provides a well-rounded introduction to the field for students, as well as a means for professional chemists, engineers, and technicians to expand and sharpen their skills in using the technology.